	Туре	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	i	LDMOS or (Lateral adj Double adj diffused adj (MOS))	:	
2	BRS	L2		LDMOS or (Lateral adj Double adj diffused adj (MOS))and (drift adj region) and different adj depth	:	2000/12/1 4 12:47
3	BRS	L3		LDMOS or (Lateral adj Double adj diffused adj (MOS))and (drift adj region) and different adj depth and (high adj breakdown adj voltage)		2000/12/1 4 13:46

PATENTS OF INST 5,286,995-2) 5,583,365-3) 5,382,536-4) 5,917,222-5) 5,242,841-

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